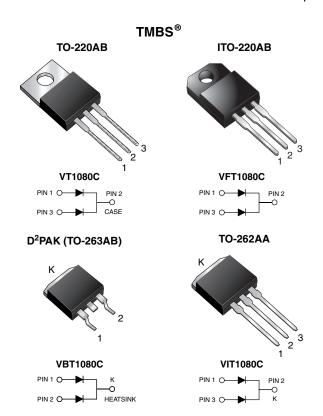


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Dual Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.49 \text{ V}$ at $I_F = 3 \text{ A}$



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 5 A					
V _{RRM}	80 V					
I _{FSM}	80 A					
V _F at I _F = 5 A	0.57 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

FEATURES





- Low forward voltage drop, low power losses
- · High efficiency operation

- (e3)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D²PAK (TO-263AB) package)
 - n RoHS
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D^2PAK (TO-263AB) and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum



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MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER		VT1080C	VFT1080C	VBT1080C	VIT1080C	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}		V				
Maximum average forward rectified current (fig. 1) per devic	e I _{F(AV)}		А				
per diode	·F(AV)	5					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	80				Α	
Non-repetitive avalanche energy at $T_J = 25~^{\circ}\text{C}$, $L = 60~\text{mH}$ per diode	E _{AS}	30				mJ	
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode	I _{RRM}	1.0			Α		
Voltage rate of change (rated V _R)	dV/dt	10 000			V/µs		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			V		
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +150				°C	

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CO	NDITIONS	SYMBOL	TYP.	MAX.	UNIT		
Breakdown voltage	I _R = 10 mA	T _A = 25 °C	V_{BR}	80 (minimum)	-	V		
Instantaneous forward voltage per diode	I _F = 3 A	T _A = 25 °C	- V _F ⁽¹⁾	0.54	-			
	I _F = 5 A			0.63	0.72	V		
	I _F = 3 A	T _A = 125 °C		0.49	-			
	I _F = 5 A			0.57	0.66			
Reverse current per diode	V - 90 V	T _A = 25 °C	I _R ⁽²⁾	12	400	μA		
	$V_{R} = 80 \text{ V}$ $T_{A} = 125 ^{\circ}$	T _A = 125 °C	'R (=)	6	15	mA		

Notes

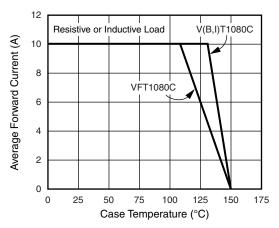
 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

 $^{(2)}$ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	VT1080C	VFT1080C	VBT1080C	VIT1080C	UNIT	
Typical thermal resistance	per diode	$R_{ heta JC}$	3.5	6.5	3.5	3.5	°C/W
	per device		2.5	5.5	2.5	2.5	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	VT1080C-E3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VFT1080C-E3/4W	1.70	4W	50/tube	Tube			
D ² PAK (TO-263AB)	VBT1080C-E3/4W	1.35	4W	50/tube	Tube			
D ² PAK (TO-263AB)	VBT1080C-E3/8W	1.35	8W	800/reel	Tape and reel			
TO-262AA	VIT1080C-E3/4W	1.43	4W	50/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)



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Fig. 1 - Maximum Forward Current Derating Curve

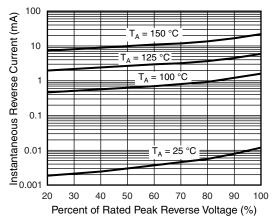


Fig. 4 - Typical Reverse Characteristics Per Diode

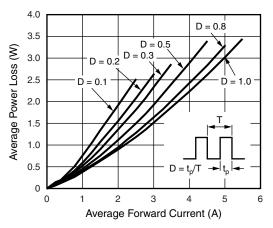


Fig. 2 - Forward Power Loss Characteristics Per Diode

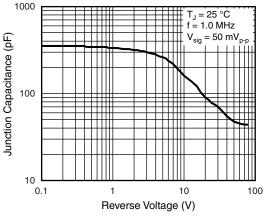


Fig. 5 - Typical Junction Capacitance Per Diode

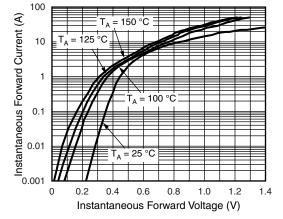


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

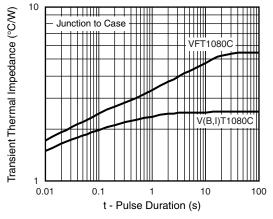
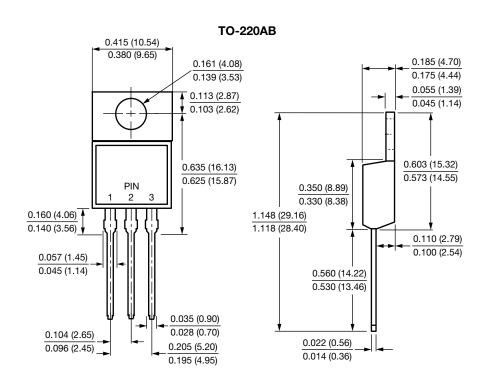


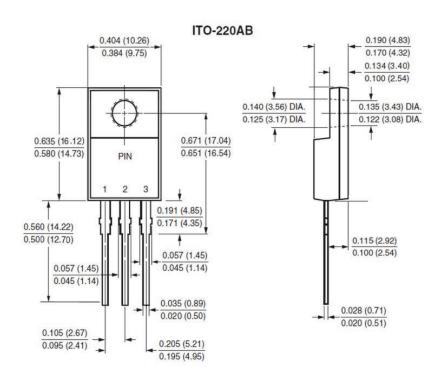
Fig. 6 - Typical Transient Thermal Impedance Per Diode

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

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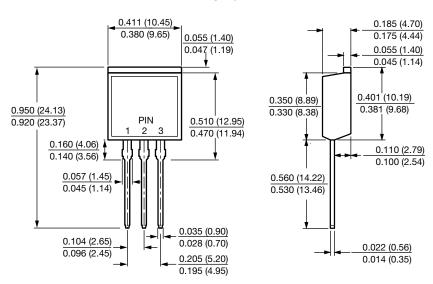




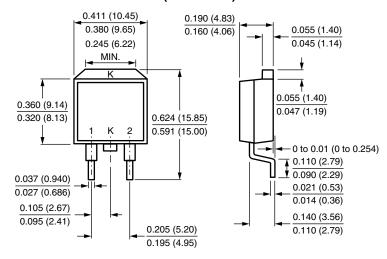
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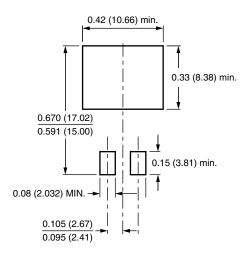
TO-262AA



D²PAK (TO-263AB)



Mounting Pad Layout





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